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TECHNICAL REPORT No. 9

SOLID-PHASE EQUILIBRIA FOR METAL-SILICON-OXYGEN TERNARY SYSTEMS: II: Sc, Y, AND La

by

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Prepared for

Chemical Materials



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February, 1991

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Haojie Yuan and R. Stanley Williams 13a TYPE OF REPORT Tech. Rpt. #9 13b TIME COVERED FROM June '90 TOFeb'91 14 Date of Report (Year, Month, Day) 15 PAGE COUNT 11 pp 6 Figs 15 SUPPLEMENTARY NOTATION 16 SUBJECT TERMS (Continue on reverse if necessary and identify by block number) ternary phase diagrams – thermodynamics – phase stability – Y-Si-O – La-Si-O – three-element systems –metal oxides – high-T _C superconductors – interfacial chemistry 18 ABSTRACT (Continue on reverse if necessary and identify by block number) We have derived ternary-phase diagrams of the type M-Si-O, where M=Sc, Y and La under the conditions of 298K and 1 atm oxygen partial pressure. These phase diagrams provide a direct view of the thermodynamics that governs stabilities of phases containing these elements in contact with each other, and should be useful for integrating Y- and La-based oxide superconductors with Si.						
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Solid phase equilibria for metal-silicon-oxygen ternary systems II: Sc. Y and La

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Abstract

We have derived ternary phase diagrams of the type M-Si-O, where M=Sc, Y and La under the conditions of 298K and 1atm oxygen partial pressure. These phase diagrams provide a direct view of the thermodynamics that governs stabilities of phases containing these elements in contact with each other, and should be useful for integrating Y- and La-based oxide superconductors with Si.

I. Introduction

The application of ternary phase diagrams to research on thin film structures has been recognized by many investigators. 1-6 A ternary phase diagram provides a direct view of the thermodynamics that govern the stability of the phases in contact with each other in a particular three-element system. Although such phase diagrams are strictly valid only for closed bulk systems, they are very helpful

in explaining the experimental results on the stabilities of thin film structures and in predicting the reactions that occur at interfaces between different materials.

In this work, phase diagrams for systems of the type M-Si-O, where M = Sc, Y and La, have been derived. These phase diagrams are important for understanding how the metal oxides (Sc_2O_3 , Y_2O_3 and La₂O₃) and various high T_C superconductors interact with elemental Si, SiO₂ and corresponding metal silicates, how silicates interact with elemental Si, and how the metals (Sc, Y and La) interact with SiO₂. This work extends a previous examination of M-Si-O systems, where M=Mg, Ca, Sr and Ba.⁷ We will describe how the phase diagrams were determined, present the ternary diagrams for the M-Si-O systems, and discuss the use of these phase diagrams for understanding interfacial chemistry.

II. Ternary Phase Diagram Determination

Ternary phase diagrams can be determined from calculations if the Gibbs energy data of all the relevant compounds are known or by performing phase stability experiments if the thermochemical data are unavailable^{1,5} Since the Gibbs energy data for many phases in the Sc-Si-O, Y-Si-O and La-Si-O systems could not be found, we had to determine the phase diagrams for these systems by performing experiments.

We consulted the literature⁸⁻¹⁷ to determine what phases exist in each system, and constructed the binary boundaries of the ternary diagrams. In addition, all three systems have silicates that require

the existence of tie-line segments between M_2O_3 and SiO_2 . In the Sc-Si-O system, if a tie line connecting Sc_2O_3 and Si exists, then we can immediately determine all other tie lines in this system on the basis of Gibbs phase rule,⁸ i.e. no two tie-lines can cross. Thus, we selected a mixture of Sc_2O_3 and Si with relative amounts of each corresponding to the following stoichiometric reaction:

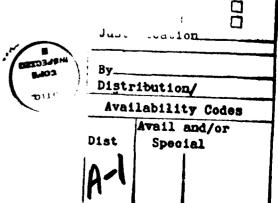
$$6Sc_2O_3 + 29Si \Rightarrow 9SiO_2 + 4Sc_3Si_5.$$

This composition corresponds to the point where the potential Sc_2O_3 -Si tie line intersects a different possibility, a SiO_2 - Sc_3Si_5 tie line.

We mixed a small amount of 99.9% pure Sc_2O_3 and 99.8% pure Si powders, sealed the mixture in a small vacuum ampoule, and heated to the temperature of 800°C for 7 days to initiate any reaction. Samples of the mixture before and after heating were analyzed by the x-ray powder diffraction method to see what phases were present in the mixture, and the results are shown in Fig. 1. The two x-ray powder diffraction patterns are nearly the same. Therefore, no new phases were produced by heating, and we deduce that Sc_2O_3 and Si form a stable pseudobinary system. There should be a tie line connecting Sc_2O_3 and Si, and all other tie lines in the system are dictated by the Gibbs phase rule.

The same type of experiments were performed for the Y-Si-O and La-Si-O systems, except that the reaction mixtures chosen for these two systems were consistent with:

$$2Y_2O_3 + 11Si \Rightarrow 3SiO_2 + 4YSi_2$$
 and $2La_2O_3 + 11Si \Rightarrow 3SiO_2 + 4LaSi_2$,



respectively. The x-ray powder diffraction patterns before and after heating for these two samples are presented in Figs. 2 and 3. We can see from the diffraction patterns that no new phases were produced in these two systems, although the relative intensities of some of the peaks did change. These changes are too small to be caused by phases transformations in the mixtures, and are most likely the result of physical changes in the powders. Thus, Si forms pseudobinary systems with both Y_2O_3 and La_2O_3 , and the diagrams for these systems are also completely determined. The resulting phase diagrams for the Sc-Si-O, Y-Si-O and La-Si-O systems are presented in Figs. 4-6, respectively.

During the experiments, we found La₂O₃ is very air sensitive. It reacts readily with H₂O and CO₂ to form hydroxides and carbonates. We collected x-ray powder diffraction patterns of both La₂O₃ powder taken directly from the reagent bottle and La₂O₃ powder that had been exposed to the air for two days, and then we compared both patterns with the pattern that we collected for Si and La₂O₃ mixed powders. Because the reaction of La₂O₃ powder with air is fairly rapid (after only two and half hours, a noticeable volume change of the La₂O₃ powder occurs), the x-ray powder pattern must be The scan times used for this study were 60 collected quickly. minutes long. The peak labeled Z in Fig. 3 is the result of phases formed by reactions of La₂O₃ with air. During the experiments, we also mixed La₂O₃ powder that had been exposed to the air for two days with Si powder, sealed a small amount of the mixture in a small vacuum ampoule and heated to 800°C. This led to an explosion of the ampoule. We deduce that this is because that La₂O₃ had

already absorbed H_2O and CO_2 in the air to form hydroxides and carbonate. These compounds decomposed upon heating and the release of gases at the high temperature caused the explosion.

III. Discussion

The phase diagrams for Sc-Si-O, Y-Si-O and La-Si-O are very similar. The only differences are the stoichiometries and number of the silicide phases and the number of silicates. These diagrams are quite different from some of those for the column II7 and column IV4.17 metal-silicon-oxygen phase diagrams. In the column II metalsilicon-oxygen systems,7 the phase diagram for the Mg-Si-O system is very similar to the phase diagrams derived in this work, but the phase diagrams for the Ca-Si-O, Sr-Si-O and Ba-Si-O systems are more complicated. Compared to the phase diagrams present in this paper, there are more oxides and silicates in the Ca-Si-O, Sr-Si-O and Ba-Si-O systems. The oxides of Ca, Sr and Ba are reduced by Si, while Sc₂O₃, Y₂O₃ and La₂O₃ are stable in contact with Si. The phase diagram for Ti-Si-O system4 is quite different from the phase diagrams derived here. There are more oxides in the Ti-Si-O system that are not stable in contact with Si, no Ti silicate exists and there are more silicides.

From the phase diagrams, we can see that the metal oxides $(Sc_2O_3, Y_2O_3 \text{ and } La_2O_3)$ are connected to silicon by tie lines. Thus, thin films of these oxides should be stable on silicon substrates. This information is potentially useful when considering the deposition of Y- and La- based superconductors on Si substrates.

Also, we can see that the oxides are stable in contact with the various metal silicides. Metal oxides react with silica to produce metal silicates, and thin films of these silicates should be stable if deposited on silicon substrates. One may think of using Y silicates silicates interlayer materials between **YBCO** 10 La as superconducting films and a silicon substrate, since ternary oxide compounds of this kind are very stable.7 However, the lattice constants of the Y and La silicates 16 are very different from those of YBCO and Si, which most likely precludes being able to grow epitaxial structures. Sc, Y and La can all reduce SiO₂ to metal oxides and metal silicides, which means that from the thermodynamic point of view, these metals cannot be stable on SiO₂ substrates.

We can use the phase diagrams we derived to make the following estimations. Taking Sc-Si-O as an example from the diagram, for the Sc_2SiO_5 -Sc and Sc_2O_3 -Si tie lines to be true, we have:

$$\Delta G(Sc_2SiO_5) < \Delta G(Sc_2O_3) + \Delta G(SiO_2)$$
 and (1)

$$5\Delta G(Sc_2O_3) < 3\Delta G(Sc_2SiO_5). \tag{2}$$

By combining (2) with (1), we have:

$$\Delta G(Sc_2O_3) < 3/2\Delta G(SiO_2), \tag{3}$$

which puts an upper bound on the Gibbs energy of formation of Sc_2O_3 . For $Sc_2Si_2O_7$, the same type of estimation also leads to the inequality in (3). The same estimates can be made in the Y-Si-O and La-Si-O systems also, and we derived the formulae corresponding to (3). The Gibbs energy data for the metal oxides and silicon dioxide are tabulated in Table I. The relations derived from the estimates made above are consistent with the literature data that exists.

Thus, the phase diagrams are consistent with the known thermochemical data for these systems.

IV. Summary

Ternary phase diagrams have been derived for the metal (Sc, Y and La)-Si-O systems. These phase diagrams can be used as guides to understand the chemistry at the interfaces of different solids involving the represented elements. They can be determined from very simple experiments, but they can provide a great deal of insight into chemical reactivity at interfaces and designing new structures based on joining unlike materials at an interface.

Acknowledgement

This work was supported in part by the Office of Naval Research. R. S. Williams received partial support from the Camille and Henry Dreyfus Foundation.

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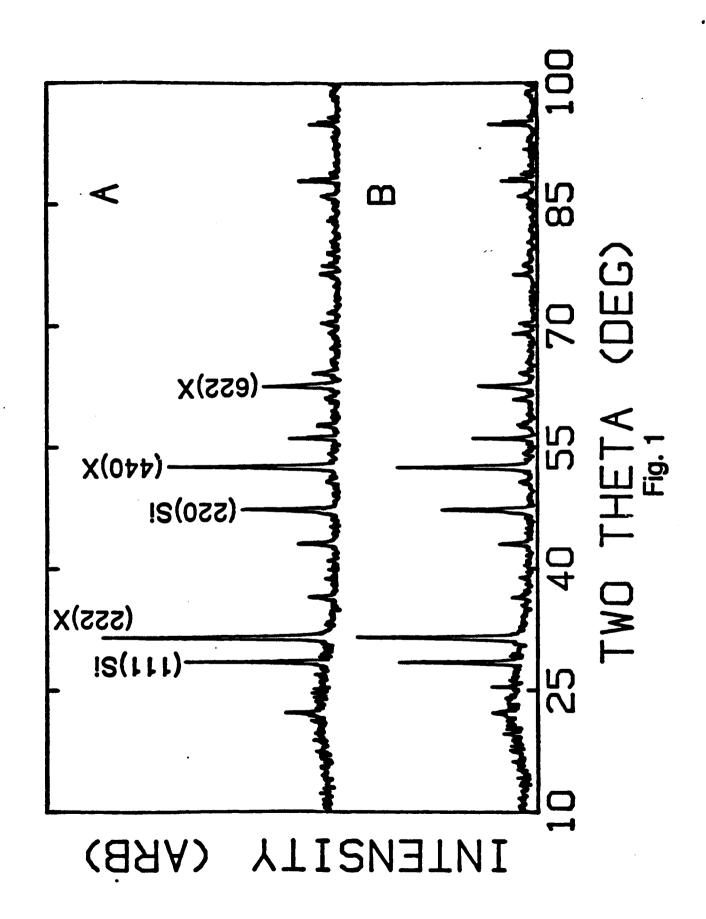
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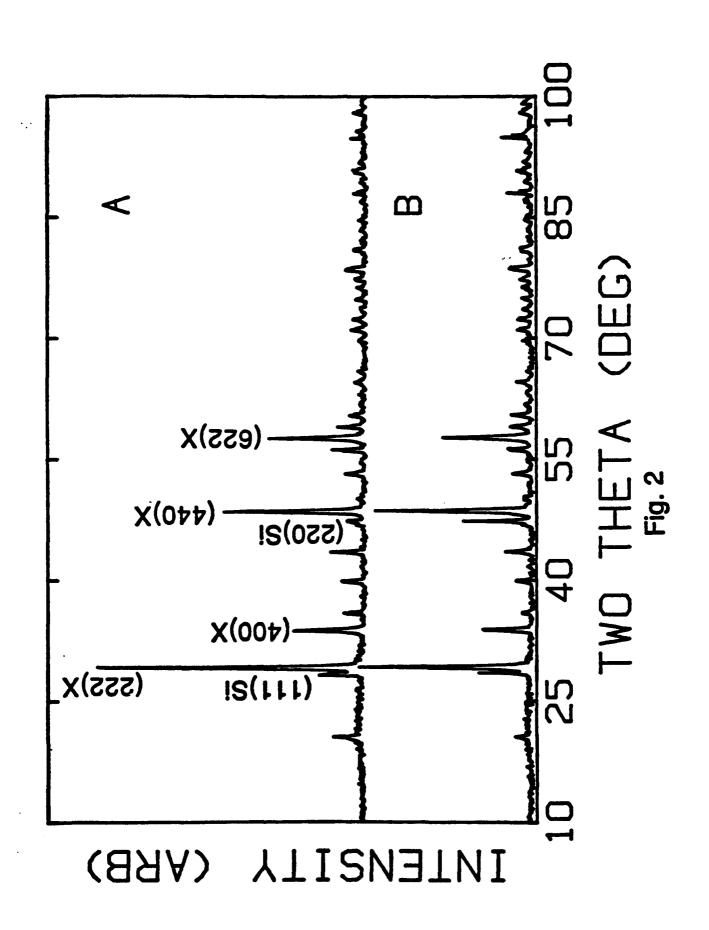
Table I. Gibbs Energy Data for the Metal Oxides and SiO₂.¹¹

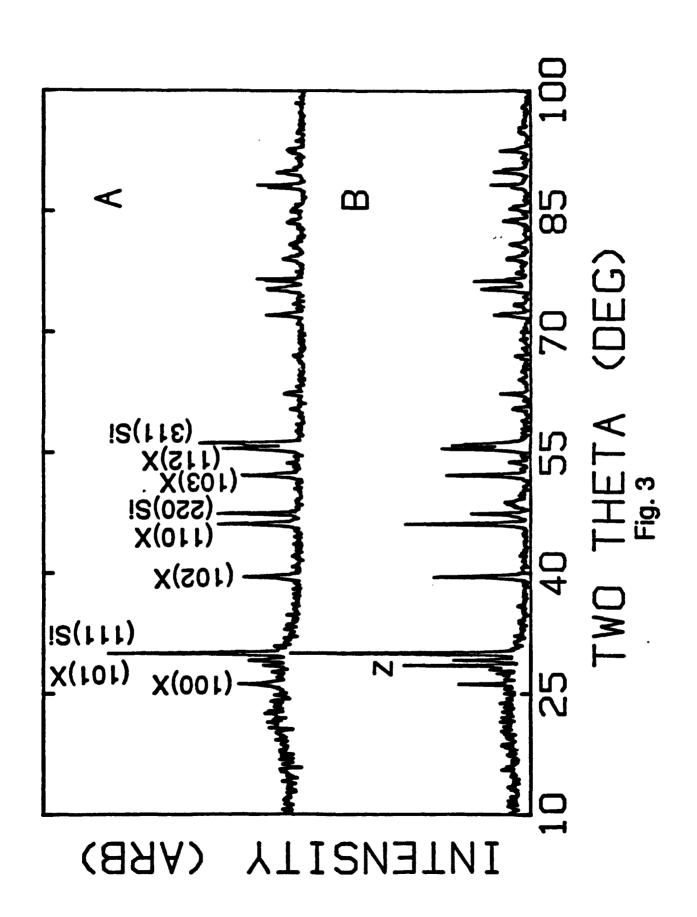
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	ΔG (M ₂ O ₃)	3/2AG(SiO ₂)		
	(kJ/mol)	(kJ/mol)		
Sc ₂ O ₃	-1819.36	-1285.0		
Y ₂ O ₃	-1816.60	-1285.0		
La ₂ O ₃	-1705.8	-1285.0		
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Figure Captions

- Fig. 1. X-ray powder diffraction pattern for the powdered mixture of Sc₂O₃ and Si. (A) After heating at 800°C for 7 days, (B) before heating. X stands for Sc₂O₃.
- Fig. 2. X-ray powder diffraction pattern for the powdered mixture of Y₂O₃ and Si. (A) After heating at 800°C for 7 days, (B) before heating. X stands for Y₂O₃.
- Fig. 3. X-ray powder diffraction pattern for the powdered mixture of La₂O₃ and Si. (A) After heating at 800°C for 7 days, (B) before heating. X stands for La₂O₃. Z is due to the phase(s) caused by exposing the La₂O₃ powder to the air while the diffraction pattern was being collected.
- Fig. 4. Sc-Si-O phase diagram at 298K and 1atm.
- Fig. 5. Y-Si-O phase diagram at 298K and 1atm. Compounds from left to right on the Y₂O₃-SiO₂ tie-line are Y₂SiO₅, Y₁₄Si₉O₃₉, Y₄Si₃O₁₂ and Y₂Si₂O₇. Y₁₄Si₉O₃₉ and Y₄Si₃O₁₂ are indicated with the same point on the diagram because their compositions are nearly indistinguishable.
- Fig. 6. La-Si-O phase diagram at 298K and 1atm. Compounds from left to right on the La_2O_3 -SiO₂ tie-line are La_2SiO_5 , $La_14Si_9O_{39}$, $La_4Si_3O_{12}$ and $La_2Si_2O_7$. $La_14Si_9O_{39}$ and $La_4Si_3O_{12}$ are indicated with the same point on the diagram because their compositions are nearly indistinguishable.







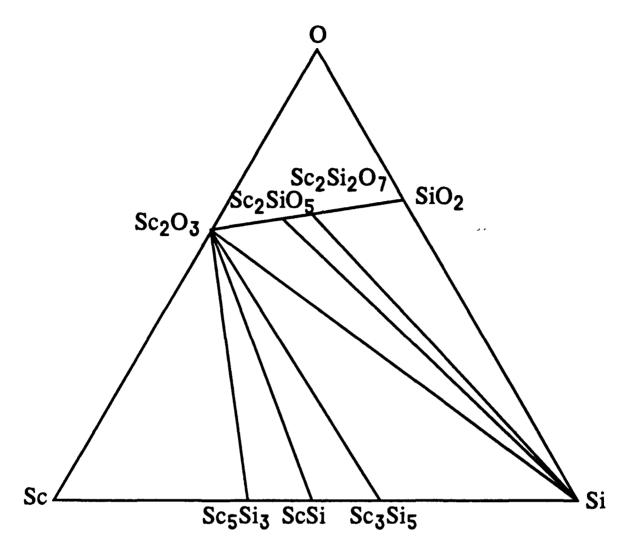


Fig. 4

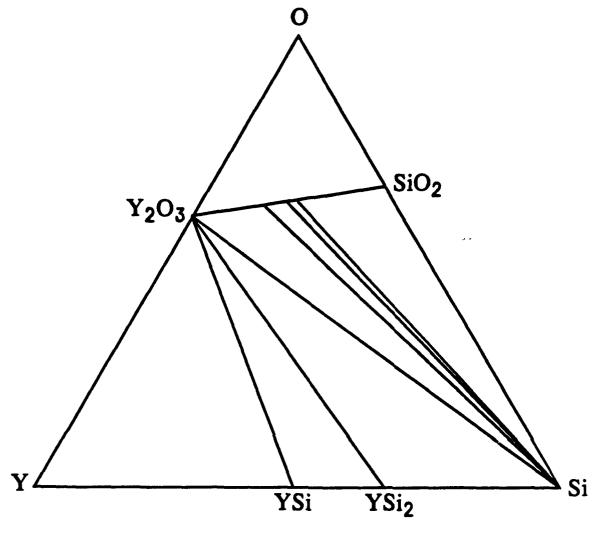


Fig. 5

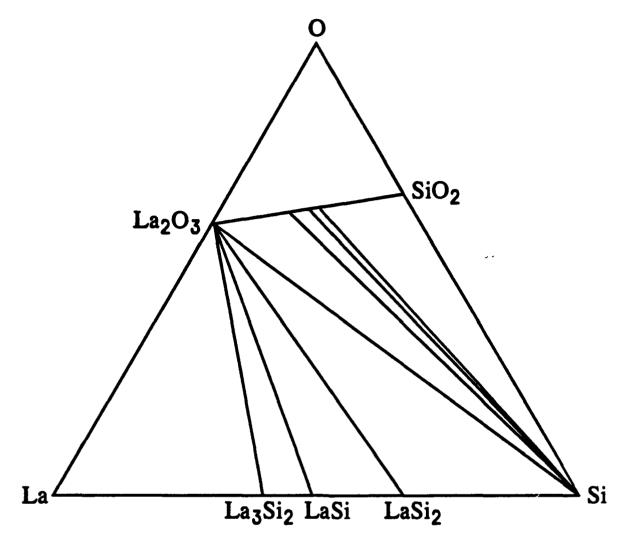


Fig. 6